NSN 5961-01-068-8834

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Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-068-8834 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **End Application:** Detecting set, infrared, an/aas-36 **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 96214-772608 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure:**